
3SK239A

GaAs Dual Gate MES FET

HITACHI

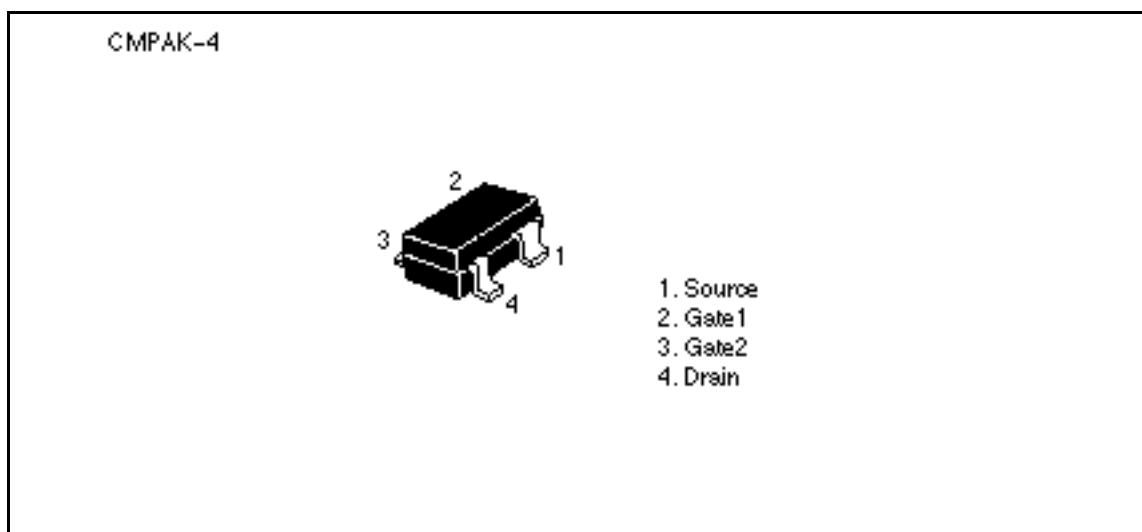
Application

UHF RF amplifier

Features

- Excellent low noise characteristics
(NF = 1.3 dB Typ at f = 900 MHz)
- Capable of low voltage operation

Outline



3SK239A

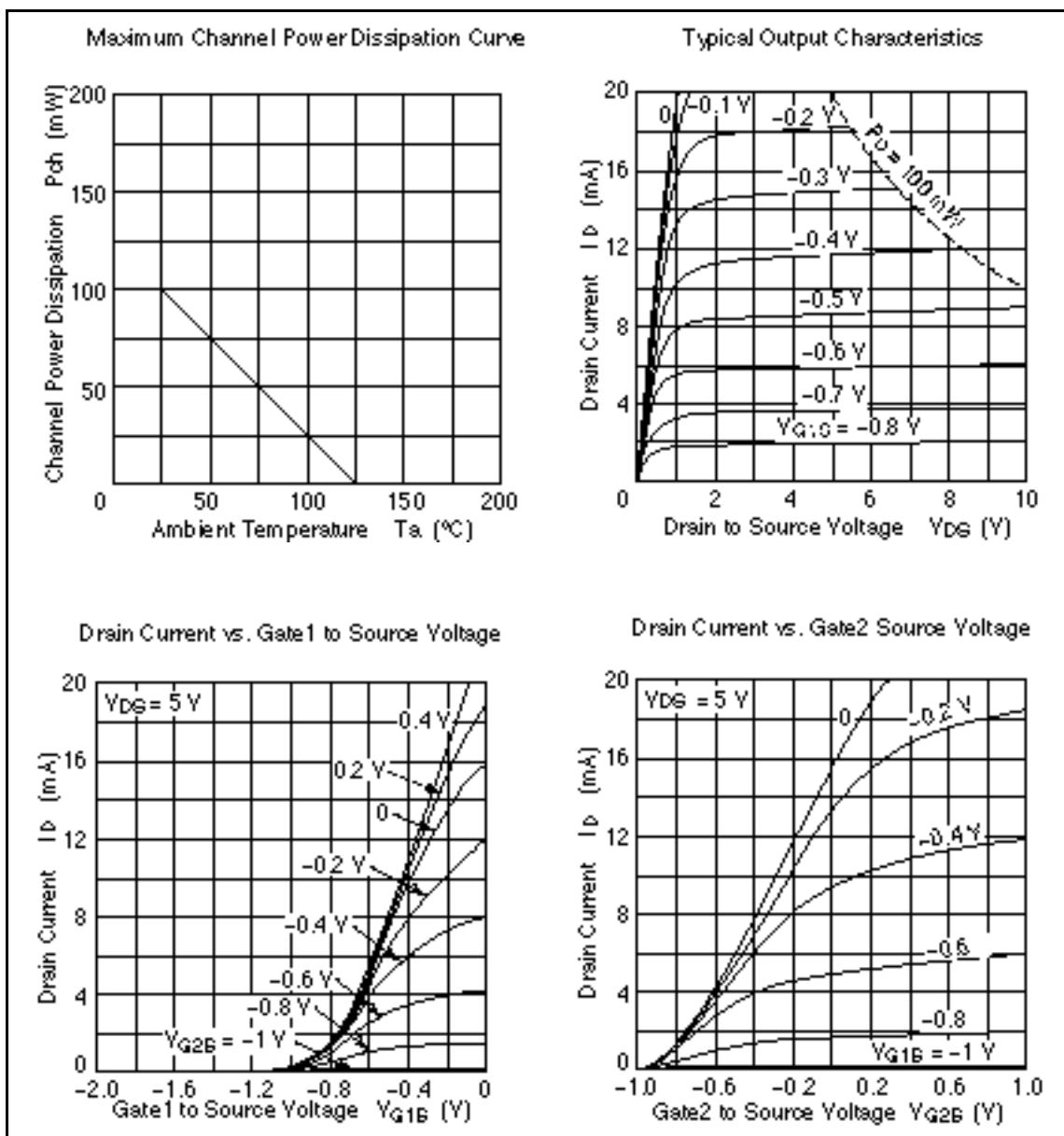
Absolute Maximum Ratings (Ta = 25°C)

Item	Symbol	Ratings	Unit
Drain to source voltage	V _{DS}	12	V
Gate 1 to source voltage	V _{G1S}	-6	V
Gate 2 to source voltage	V _{G2S}	-6	V
Drain current	I _D	50	mA
Channel power dissipation	Pch	100	mW
Channel temperature	T _{ch}	125	°C
Storage temperature	T _{tsg}	-55 to +125	°C

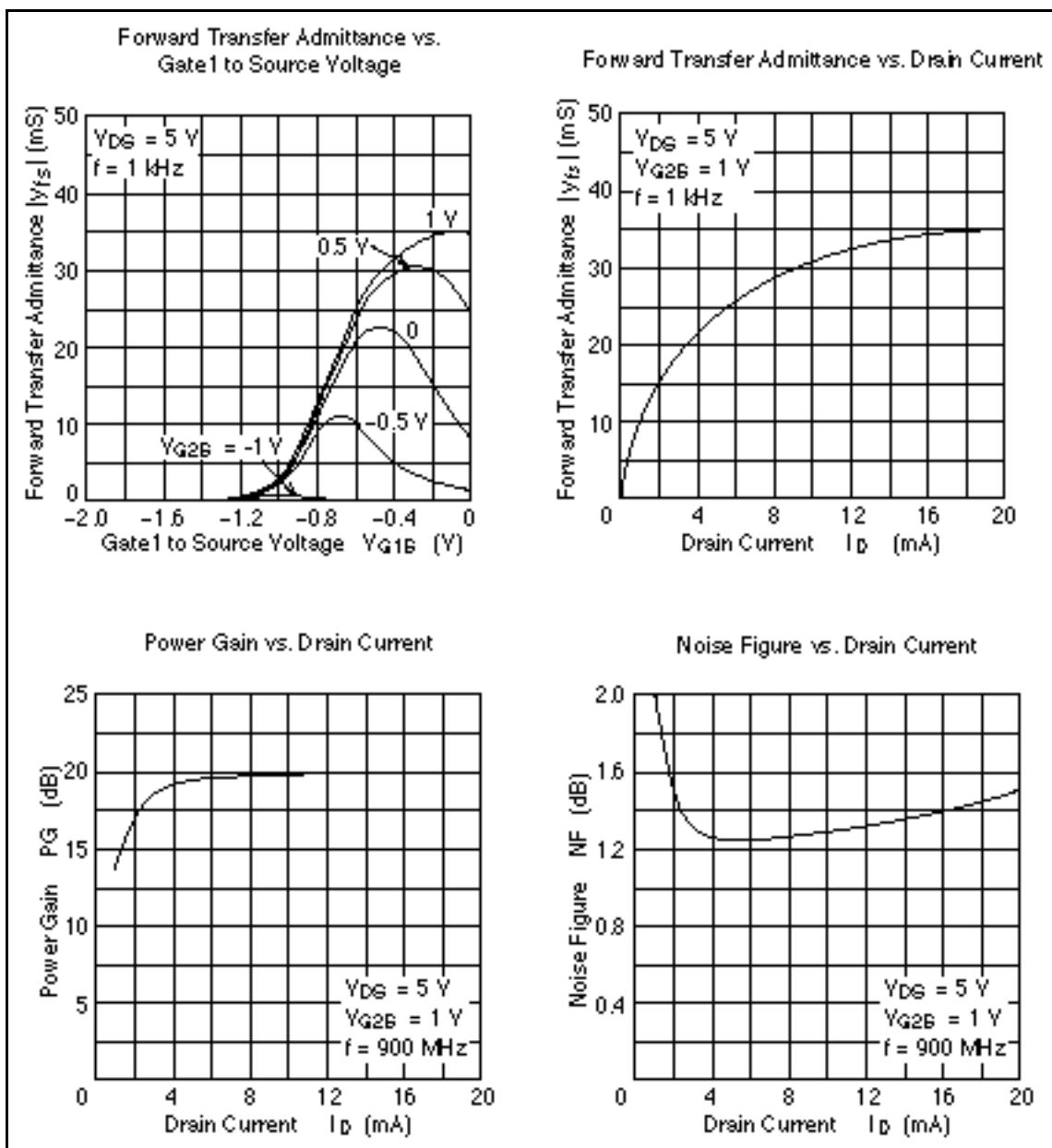
Electrical Characteristics (Ta = 25°C)

Item	Symbol	Min	Typ	Max	Unit	Test conditions
Drain to source leakage current	I _{DSX}	—	—	50	μA	V _{DS} = 12 V, V _{G1S} = -3 V, V _{G2S} = 0
Gate 1 to source breakdown voltage	V _{(BR)G1SS}	-6	—	—	V	I _{G1} = -10 μA, V _{G2S} = V _{DS} = 0
Gate 2 to source breakdown voltage	V _{(BR)G2SS}	-6	—	—	V	I _{G2} = -10 μA, V _{G1S} = V _{DS} = 0
Gate 1 leakage current	I _{G1SS}	—	—	-5	μA	V _{G1S} = -5 V, V _{G2S} = V _{DS} = 0
Gate 2 leakage current	I _{G2SS}	—	—	-5	μA	V _{G2S} = -5 V, V _{G1S} = V _{DS} = 0
Drain current	I _{DSS}	14	19	28	mA	V _{DS} = 5 V, V _{G1S} = V _{G2S} = 0
Gate 1 to source cutoff voltage	V _{G1S(off)}	—	-1.2	-1.6	V	V _{DS} = 5 V, V _{G2S} = 0, I _D = 100 μA
Gate 2 to source cutoff voltage	V _{G2S(off)}	—	-1.2	-1.6	V	V _{DS} = 5 V, V _{G1S} = 0, I _D = 100 μA
Forward transfer admittance	y _{fs}	20	31	—	mS	V _{DS} = 5 V, V _{G2S} = 1 V, I _D = 10 mA, f = 1 kHz
Input capacitance	C _{iss}	—	0.58	1.0	pF	V _{DS} = 5 V, V _{G1S} = V _{G2S} = -3 V, f = 1 MHz
Output capacitance	C _{oss}	—	0.36	0.6	pF	
Reverse transfer capacitance	C _{rss}	—	0.028	0.05	pF	
Power gain	PG	17	19	—	dB	V _{DS} = 5 V, V _{G2S} = 1 V, I _D = 10 mA, f = 900 MHz
Noise figure	NF	—	1.3	2.0	dB	

Note: Marking is "XR-".

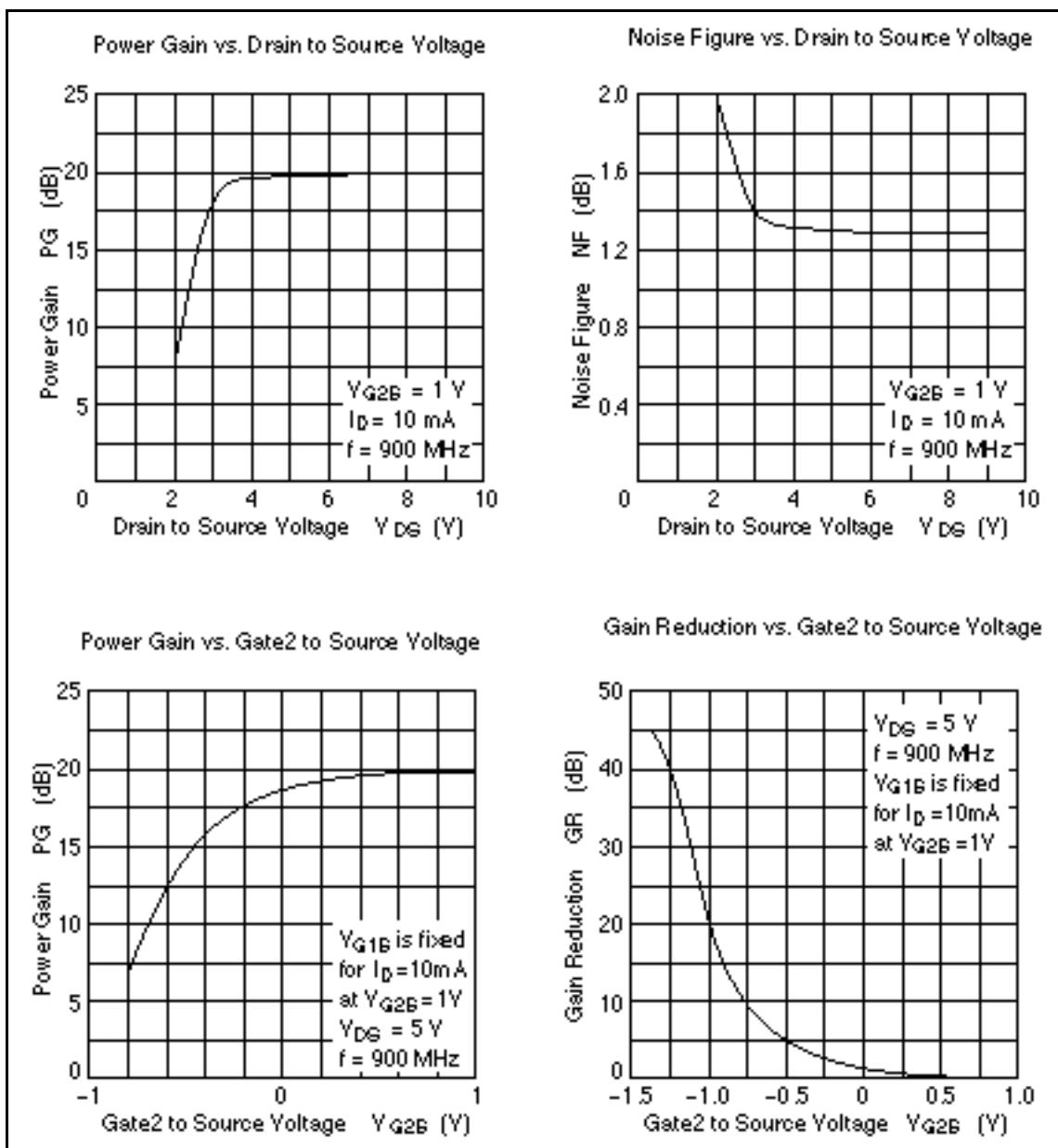


3SK239A



HITACHI

3SK239A



3SK239A

When using this document, keep the following in mind:

1. This document may, wholly or partially, be subject to change without notice.
2. All rights are reserved: No one is permitted to reproduce or duplicate, in any form, the whole or part of this document without Hitachi's permission.
3. Hitachi will not be held responsible for any damage to the user that may result from accidents or any other reasons during operation of the user's unit according to this document.
4. Circuitry and other examples described herein are meant merely to indicate the characteristics and performance of Hitachi's semiconductor products. Hitachi assumes no responsibility for any intellectual property claims or other problems that may result from applications based on the examples described herein.
5. No license is granted by implication or otherwise under any patents or other rights of any third party or Hitachi, Ltd.
6. MEDICAL APPLICATIONS: Hitachi's products are not authorized for use in MEDICAL APPLICATIONS without the written consent of the appropriate officer of Hitachi's sales company. Such use includes, but is not limited to, use in life support systems. Buyers of Hitachi's products are requested to notify the relevant Hitachi sales offices when planning to use the products in MEDICAL APPLICATIONS.

HITACHI

Hitachi, Ltd.

Semiconductor & IC Div.
Nippon Bldg, 2-6-2, Otemachi, Chiyoda-ku, Tokyo 100, Japan
Tel Tokyo (03) 3270-2111
Fax (03) 3270-5100

For further information write to:

Hitachi America, Ltd.
Semiconductor & IC Div.
2000 Sierra Point Parkway
Brisbane, CA. 94005-4835
U.S.A.
Tel 415-599-8300
Fax 415-593-4207

Hitachi Europe GmbH
Electronic Components Group
Continental Europe
D-85622 Fildkirchen
München
Tel 089-9 91 80-0
Fax 089-9 29 30 00

Hitachi Europe Ltd.
Electronic Components Div.
Northern Europe Headquarters
Whitebrook Park
Lower Cookham Road
Maidenhead
Berkshire SL6 8YA
United Kingdom
Tel 0628-585000
Fax 0628-779322

Hitachi Asia Pte. Ltd
#6 Collyer Quay #20-00
Hitachi Tower
Singapore 0104
Tel 535-2100
Fax 535-1533
Hitachi Asia (Hong Kong) Ltd.
Unit 705, North Tower,
World Finance Centre
Harbour City, Canton Road
Tsim Sha Tsui, Kowloon
Hong Kong
Tel 27359218
Fax 27306074

HITACHI